

isc N-Channel MOSFET Transistor

AOT12N65

FEATURES

- Drain Current –I_D=12A@ T_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V_{DSS}=650V(Min)
- Static Drain-Source On-Resistance
- : R_{DS(on)} = 0.72 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

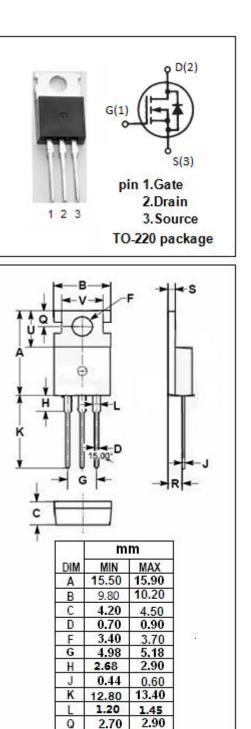
• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25 C)						
SYMBOL	PARAMETER VA		UNIT			
V _{DSS}	Drain-Source Voltage	650	V			
V _{GS}	Gate-Source Voltage-Continuous	±30	V			
ID	Drain Current-Continuous	12	А			
I _{DM}	Drain Current-Single Pluse	48	А			
PD	Total Dissipation @T _c =25°C 278		W			
TJ	Max. Operating Junction Temperature -55~150		°C			
T _{stg}	Storage Temperature -55~150		°C			

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.45	°C/W



2.70

1.35

6.65

8.86

2.30

1.29

6.45 8.66

isc website: <u>www.iscsemi.com</u> ¹ isc & isc

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	650		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 5V; I _D = 0.25mA	3	4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 6A		0.72	Ω
lgss	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 650V; V_{GS} = 0 V_{DS} = 520V; V_{GS} = 0@T _J =125°C		1 10	μA
V _{SD}	Forward On-Voltage	I _S = 1A; V _{GS} = 0		1	V

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